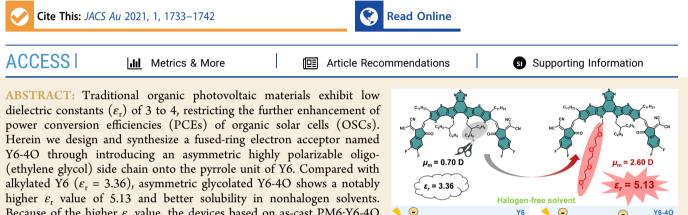


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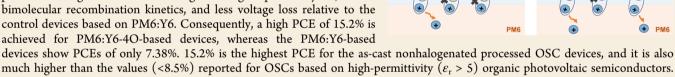
Article

Asymmetric Glycolated Substitution for Enhanced Permittivity and Ecocompatibility of High-Performance Photovoltaic Electron Acceptor

Tengfei Li, Kang Wang, Guilong Cai, Yawen Li, Heng Liu, Yixiao Jia, Zhenzhen Zhang, Xinhui Lu, Ye Yang,* and Yuze Lin*



alkylated Y6 ($\varepsilon_r = 3.36$), asymmetric glycolated Y6-4O shows a notably higher ε_r value of 5.13 and better solubility in nonhalogen solvents. Because of the higher ε_r value, the devices based on as-cast PM6:Y6-4O processed using toluene exhibit a higher charge separation yield, slower bimolecular recombination kinetics, and less voltage loss relative to the control devices based on PM6:Y6. Consequently, a high PCE of 15.2% is achieved for PM6:Y6-4O-based devices, whereas the PM6:Y6-based



KEYWORDS: organic solar cells, nonfullerene acceptor, high permittivity, ecocompatibility, oligo(ethylene glycol)

INTRODUCTION

Thanks to their low weight, intrinsic flexibility, semitransparency and large-area processability, organic solar cells (OSCs) have gained broad interest as a promising photovoltaic technology.¹⁻⁴ In particular, in the past 5 years, owing to the rapid development of fused-ring electron acceptors (FREAs), the power conversion efficiencies (PCEs) of OSCs have reached 18%.⁵⁻²⁰ However, in comparison with conventional inorganic (e.g., silicon, GaAs) solar cells and hybrid perovskite solar cells, the performance of OSCs still greatly lags behind.²¹ One of the significant limitations for the further PCE enhancement of OSCs is the relatively low dielectric constant (ε_r) of traditional organic photovoltaic semiconductors (ε_r of 3 to 4), which limits the exciton dissociation efficiency.²² In contrast, the typical inorganic/hybrid semiconductors exhibit higher ε_r values (Si: ~12, GaAs: ~12, and perovskite: ~18).²³⁻²⁵ A high ε_r can reduce the Coulomb attraction within excitons, facilitating the charge separation at the donor/ acceptor interface with decreased charge recombination possibility, which can boost the device efficiency enhancement.²⁶ A small exciton binding energy $(E_{\rm b})$ given a value close to thermal energy $k_{\rm B}T$ ($k_{\rm B}$ is the Boltzmann constant, T is the absolute temperature) can make it promising for OSCs to acquire an enhanced PCE of >20%.22

In recent years, very limited approaches have been reported to enhance the permittivity of organic semiconductors, including the introduction of polarizable units (e.g., cyano groups, fluorine atoms, and oligo(ethylene glycol) (OEG) side chains) on the molecular skeleton and the addition of highpermittivity materials in the photoactive layer.²⁷ However, the other imperfect intrinsic properties of these high-permittivity materials, such as the absorption, energy level, and charge transport, restrain the upper limit of their photovoltaic performance.²⁸⁻³² In addition, most studies acquired high permittivity but brought some negative effects on the crystallinity and compatibility in active layer, which play significant roles in the device optimization.^{26,33} Therefore, it is full of significance and challenge to rationally design highdielectric-constant organic semiconductors holding excellent photovoltaic performance.

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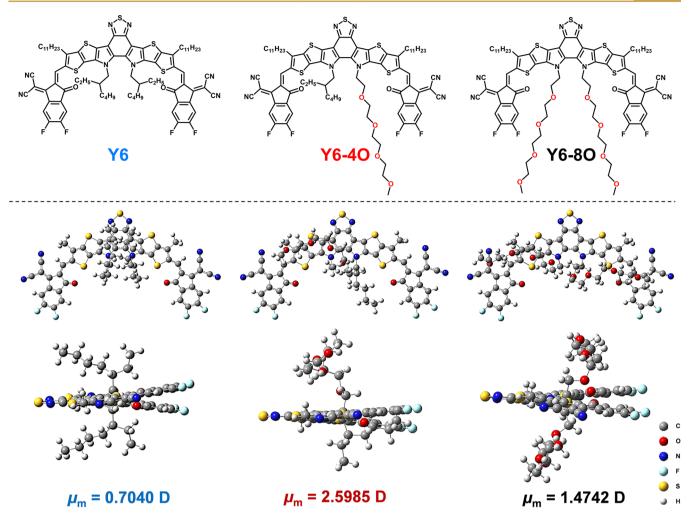


Figure 1. Chemical structures, dipole moments, and optimal geometries (alkyl groups attaching to thiophene are simplified to methyl) calculated by the Gaussian 09 program at the B3LYP/6-31G* level of Y6, Y6-4O, and Y6-8O.

Here we proposed a rational molecular design strategy named "asymmetric glycolated substitution" for the enhanced permittivity and ecocompatibility of high-performance photovoltaic electron acceptors. We designed and synthesized the FREA Y6-4O via introducing an asymmetric OEG side chain instead of one alkyl side chain on the pyrrole unit of Y6.¹³ Compared with Y6 (ε_r = 3.30 ± 0.05), Y6-4O exhibited a higher dielectric constant of 4.77 ± 0.27 , with a highest value of 5.13, leading to enhanced exciton dissociation and decreased charge recombination in OSC devices. Meanwhile, the introduction of a hydrophilic polarizable glycolated side chain can obviously increase the solubility of Y6-4O in nonhalogen solvents, which benefits the fabrication of greensolvent-processed OSCs and reduces the harm to human health and the environment.³⁴ When blended with polymer donor PM6, the as-cast devices based on glycolated Y6-4O processed using toluene showed a high PCE of 15.2%, notably better than that of the control devices based on the alkylated Y6 acceptor (7.38%). 15.2% is the highest PCE for the as-cast nonhalogenated processed OSC devices and the record PCE for OSCs based on high-permittivity ($\varepsilon_r > 5$) organic semiconductors.

RESULTS AND DISCUSSION

Dipole Moment

The dielectric constant of a material can be described by the Debye equation 35

$$\frac{\varepsilon_{\rm r}-1}{\varepsilon_{\rm r}+2} = \frac{4\pi}{3} N \left(\alpha_{\rm e} + \alpha_{\rm d} + \frac{\mu_{\rm m}^2}{3k_{\rm B}T} \right)$$

where N is the number density of dipoles, α_{e} is the electronic polarization, α_d is the distortion polarization, and μ_m is the dipole moment. According to the Debye equation and previous work, the enhancement of the dipole moment of the molecule generally leads to a higher dielectric constant.^{36,37} Compared with symmetric molecular structures, asymmetric structures usually result in a longer distance between the centers of positive and negative charges, which benefits the enhancement of dipole moments. The density functional theory calculation was used to figure out how the asymmetric introduction of a polarizable side chain affects the μ_m value of photovoltaic materials by taking Y6 and the IDIC³⁸ molecular skeleton as examples. As a result, the dipole moment of Y6-4O with one OEG side chain was 2.60 D, which was indeed higher than those of Y6 (0.70 D) without an OEG side chain and Y6-80 with two OEG side chains (1.47 D) (Figure 1). The same variation change in dipole moment was also seen in the IDIC

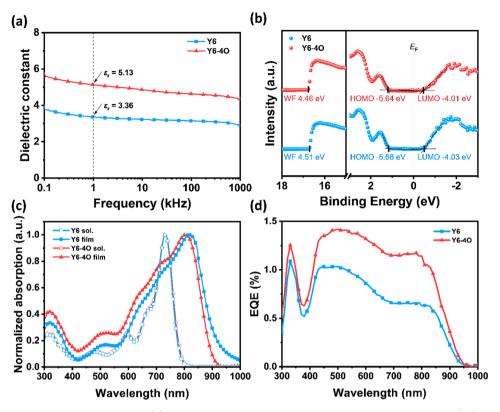


Figure 2. (a) Dielectric constant versus frequency, (b) UPS and LEIPS spectra with respect to the Fermi energy level (E_F) at 0 eV (work function (WF) values are labeled), (c) absorption spectra, and (d) EQE spectra of single-component devices of Y6 and Y6-4O.

skeleton before and after the asymmetric (IDIC-8O) and symmetric (IDIC-16O) replacement of the alkyl side chain by a polarizable side chain (Figure S1), which supports the universality of the asymmetric substituent enhancing molecular dipole moments.

Synthesis of Y6-40

Y6-4O with a higher calculated $\mu_{\rm m}$, which was expected to behave with high permittivity, was synthesized to construct photovoltaic devices. The detailed synthetic route for Y6-4O is shown in Scheme S1. The fused-ring unit with asymmetric side chains (compound 6) was synthesized with dithienothiophen-[3,2-b]-pyrrolobenzothiadiazole via two-step nucleophilic substitution reactions with 13-iodo-2,5,8,11-tetraoxatridecane and 3-(bromomethyl)heptane, respectively. It is worth noting that during the second step of the substitution reaction, to improve the reactivity, CsCO₃ with a stronger nucleophilic ability was used to replace KOH used in the first step of the reaction. Then, formylated compound 7 was obtained via a Vilsmeier-Haack reaction using anhydous dimethylformamide and POCl₃. Finally, the target molecule Y6-4O was afforded by a Knoevenagel condensation between compound 7 and 3-(1,1dicyanomethylene)-5,6-difluoro-1-indanone.³⁹ All of the new compounds were fully characterized by spectroscopic methods. (See the Supporting Information.)

Dielectric Constant and Exciton Binding Energy

We studied the dielectric constants of Y6-4O and Y6 through the parallel-plate capacitance measurement with impedance spectroscopy. The device structure was indium tin oxide (ITO)/poly(3,4-ethylenedioxythiophene):poly- $(styrenesulfonate) (PEDOT:PSS)/test film/Ca/Al. The <math>\varepsilon_r$ value can be obtained from the equation $C = \varepsilon_0 \varepsilon_{\rm r} A/d$

where C is the measured capacitance, ε_0 is the permittivity of free space, A is the device area, and d is the thickness of the test film. The dielectric constants are plotted in Figure 2a as a function of the frequency. In the test frequency range (0.1 -1000 kHz), Y6 showed a common ε_r of 2.8 to 3.8, whereas Y6-40 exhibited a notably higher ε_r of 4.4 to 5.7. At a frequency of 1 kHz (a common frequency for the comparison of ε_r values²⁶), Y6 exhibited a ε_r of 3.30 ± 0.05 with a maximum of 3.36, obviously lower than that of Y6-4O (4.77 \pm 0.27 with a maximum of 5.13). The enhancement of the dielectric property originates from the molecular asymmetry and the flexibility of the OEG side chain, which is beneficial for the reorientation of the dipole moment.⁴⁰ $E_{\rm b}$ can be approximately regarded as the Coulomb attraction between the hole and the electron in the exciton, which is inversely proportional to the dielectric constant.⁴¹ Therefore, we can reasonably deduce that the $E_{\rm h}$ of Y6-4O could be smaller than that of Y6.

The E_b can be obtained from the difference between the transport gap (E_g^{t}) and the optical band gap (E_g^{opt}) . E_g^{t} is defined as the difference between the lowest unoccupied molecular orbital (LUMO) and the highest occupied molecular orbital (HOMO) energy. E_g^{opt} is defined as the lowest optical transition (the energy between the ground state and the lowest excited state) that results in the formation of an exciton.⁴² From the measurement result of the ultraviolet photoelectron spectroscopy (LEIPS) (Figure 2b), Y6-4O exhibited slightly higher energy levels (LUMO/HOMO: -4.01/-5.64 eV) than those of Y6 (LUMO/HOMO: -4.03/-5.68 eV), which indicates that the introduction of an asymmetric OEG side chain has a negligible impact on the

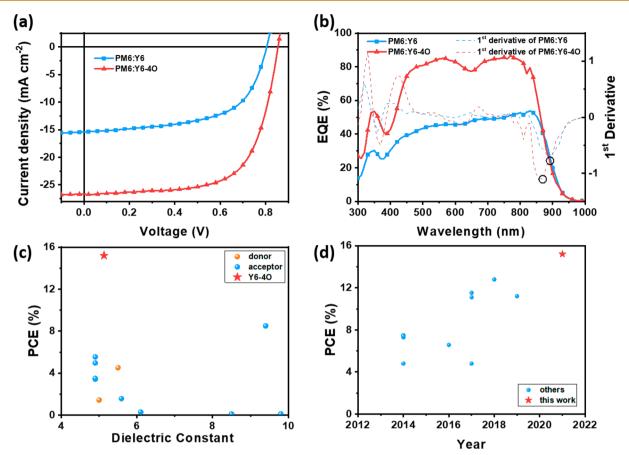


Figure 3. (a) J-V curves and (b) EQE spectra with first derivative curves of the devices based on as-cast PM6:Y6 and PM6:Y6-4O processed using toluene. Summarized PCEs for (c) the recently reported OSCs based on high-dielectric-constant organic semiconductors and (d) the recently reported as-cast OSCs processed using nonhalogen solvents.

Table 1. Photovoltaic Performances of	of As-Cast	OSCs	Processed	Using	Toluene
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active layer	$V_{\rm OC} ({\rm V})^a$	$J_{\rm SC} \ ({\rm mA} \ {\rm cm}^{-2})^a$	FF (%) ^a	PCE (%) ^a	calc. $J_{\rm SC}$ (mA cm ⁻²)
PM6:Y6	$0.804 \pm 0.002 \ (0.804)$	$15.3 \pm 0.4 (15.4)$	58.2 ± 0.9 (59.6)	$7.17 \pm 0.16 (7.38)$	15.4
PM6:Y6-4O	$0.850 \pm 0.006 \ (0.854)$	$26.1 \pm 0.3 (26.7)$	$67.2 \pm 0.6 \ (66.4)$	$14.9 \pm 0.1 (15.2)$	25.4
^a Average values w	vith standard deviation were	obtained from 10 devices	s, and the values in brac	kets are the parameters o	of the best device.

energy levels.²⁹ E_g^{t} values were calculated to be 1.65 eV for Y6 and 1.63 eV for Y6-4O, respectively. In the meantime, the CHCl₃-cast film of Y6-4O exhibited slightly blue-shifted absorption with an E_g^{opt} of 1.39 eV, relative to Y6 with an E_g^{opt} of 1.35 eV, calculated from the absorption onset (Figure 2c). As a result, the E_b of Y6-4O (0.24 eV) was smaller than that of Y6 (0.30 eV), which is consistent with the result deduced from ε_r .

Photovoltaic Performance

To study the effect of asymmetric polarizable OEG introduction on exciton dissociation, we fabricated singlecomponent devices with a structure of ITO/PEDOT:PSS/ active layer/PDINN⁴³/Ag. Y6-based devices showed a $J_{\rm SC}$ of 0.316 mA cm⁻² (Table S1). In contrast, the devices based on Y6-4O exhibited an enhanced $J_{\rm SC}$ of 0.476 mA cm⁻², which was supported by the improvement in the external quantum efficiency (EQE) response (Figure 2d). For single-component devices, the efficiency of the photocurrent generation is mainly related to the efficiency of the photon absorption (η_A), exciton dissociation ($\eta_{\rm ED}$), charge transport (η_T), and charge collection ($\eta_{\rm CC}$).⁴⁴ Each process was analyzed to figure out which contributed to the increase in $J_{\rm SC}$. The maximum molar extinction coefficient of Y6-4O ($1.7 \times 10^5 \,\mathrm{M^{-1} \, cm^{-1}}$) was a little lower than that of Y6 ($1.9 \times 10^5 \,\mathrm{M^{-1} \, cm^{-1}}$), and the $E_g^{\rm opt}$ of Y6-4O was larger than that of Y6, which implies that the η_A of the Y6-4O-based device is lower than that of the Y6-based device. According to the space-charge-limited current (SCLC)⁴⁵ method, Y6-4O had a lower electron mobility (μ_e) value of 0.92 × 10⁻⁴ cm² V⁻¹ s⁻¹ than that of Y6 ($\mu_e = 2.0 \times 10^{-4} \,\mathrm{cm^2 \, V^{-1} \, s^{-1}}$), suggesting that the η_T of the device based on Y6-4O is lower than that of the Y6-based device. Hence, the increase in $J_{\rm SC}$ for Y6-4O-based devices was likely to be attributed to the better exciton dissociation caused by its higher dielectric constant.⁴⁴

To study the photovoltaic performance of Y6-4O as an electron acceptor, we blended the commercial polymer PM6⁴⁶ (Figure S3) as the donor material for its complementary absorption spectra and matched energy levels (Figure S4). The device structure of ITO/PEDOT:PSS/active layer/PDINN/ Ag was employed. Taking the excellent solubility of glycolated Y6-4O into account, we processed the active layer with several

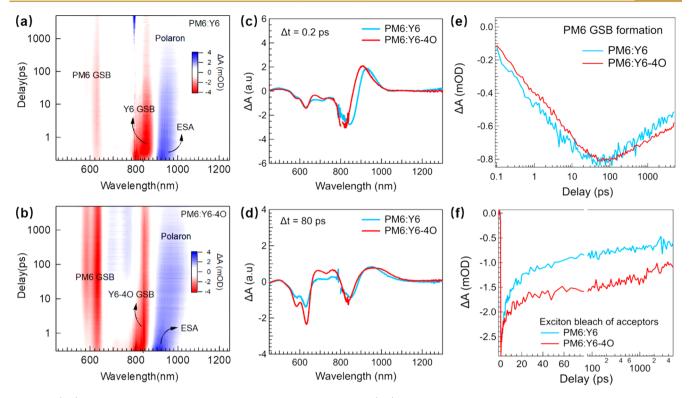


Figure 4. (a,b) Broadband TA data of PM6:Y6 and PM6:Y6-4O blend films. (c,d) TA spectra of PM6:Y6 and PM6:Y6-4O blend films at delay times of 0.2 and 80 ps. (e) TA kinetics of PM6 GSB in PM6:Y6 and PM6:Y6-4O blend films. (f) TA kinetics of the exciton bleach of acceptors in PM6:Y6 and PM6:Y6-4O blend films.

nonhalogen solvents (toluene (TL), xylene, and tetrahydrofuran) without any other treatment (Table S2), which benefitted the reduction of pollution to the environment. Consequently, the toluene-processed PM6:Y6-4O-based devices showed the best device performance: an open-circuit voltage (V_{OC}) of 0.854 V, J_{SC} of 26.7 mA cm⁻², fill factor (FF) of 66.4%, and PCE of 15.2% (Figure 3a, Table 1). By contrast, the control devices based on PM6:Y6 showed a lower V_{OC} of 0.804 V, J_{SC} of 15.4 mA cm⁻², FF of 59.6%, and PCE of 7.38%. The J_{SC} values calculated by integrating the EQE spectra with the AM 1.5G reference spectrum were close to those obtained from J-V measurements with a mismatch of <5% (Figure 3b). In comparison with the PM6:Y6-based devices with a low EQE response of about 40~50%, the PM6:Y6-4O system exhibited a significantly increased EQE > 75% in the range of 450-800nm. It is worth noting that 15.2% is the highest PCE for the ascast nonhalogenated processed OSC devices and the record PCE for OSCs based on high-permittivity ($\varepsilon_r > 5$) organic semiconductors (Figure 3c,d, Tables S3 and S4).

Exciton Dissociation and Charge Separation

The exciton dissociation probability P(E,T) was studied by the determination of the photocurrent density $(J_{\rm ph})$ as a function of the effective voltage $(V_{\rm eff})$ (Figure S5).⁴⁷ P(E,T) is equal to $J_{\rm ph}/J_{\rm sat}$ where $J_{\rm sat}$ is the saturated photocurrent density. When $V_{\rm eff}$ was higher than 2 V, the $J_{\rm ph}$ values became saturated and were estimated to be 27.5 mA cm⁻² for devices based on PM6:Y6-4O and 17.1 mA cm⁻² for devices based on PM6:Y6. Under short-circuit conditions, the P(E,T) value of the devices based on PM6:Y6-4O was 0.96, which was much higher than that of PM6:Y6-based devices (0.90). This result implies that the exciton dissociation efficiency is better for the PM6:Y6-4O system and agrees well with the higher $\varepsilon_{\rm r}$ value of Y6-4O.

The exciton dissociation kinetics is closely related to the driving force ($\Delta E_{\rm CT}$), which is defined as the difference between the band gap of the blend film ($E_{\rm g}^{\rm PV}$) and the energy of the charge-transfer (CT) state ($E_{\rm CT}$).⁴⁸ The $E_{\rm g}^{\rm PV}$ values for PM6:Y6 and PM6:Y6-4O were 1.39 and 1.42 eV, respectively, which were extracted from the maximum of the absolute value of the first derivative of EQE spectra in the low-energy region (Figure 3b).⁴⁹ The $E_{\rm CT}$ was deduced by fitting to the low-energy part of the Fourier-transform photocurrent spectroscopy EQE (FTPS-EQE) spectra.^{50,51} From Figure S6, the $E_{\rm CT}$ values for PM6:Y6 and PM6:Y6-4O can be obtained as 1.35 and 1.38 eV, respectively. Consequently, both devices showed small $\Delta E_{\rm CT}$ values of 0.04 eV, indicating the same driving force for charge transfer and separation in the devices.

The transient absorption (TA) spectroscopy was carried out to further investigate the charge separation yield in the PM6:Y6 and PM6:Y6-40 films.^{52,53} The experimental conditions are described in the Supporting Information. Despite the distinct dielectric constants, we found that Y6 and Y6-4O films showed identical exciton recombination dynamics, which were represented by the ground-state bleach (GSB) recovery kinetics (Figure S7). This observation implies that the introduction of an asymmetric OEG polarized side chain has a negligible impact on the exciton lifetime. Given the well-separated absorption peaks between acceptors and donors, we can tune the pump wavelength to selectively excite the acceptors (i.e., Y6 and Y6-4O) and avoid the excitation of PM6 in the blend films (Figure S4). As shown in Figure 4a,b, a negative peak centered at 830 nm appeared immediately after the optical excitation, corresponding to the S₁ exciton bleach of Y6/Y6-4O. The positive peaks at the lower energy side of the exciton bleach are then primarily attributed to the excited-state absorption (ESA).⁵⁴ Meanwhile, other bleach signals were also

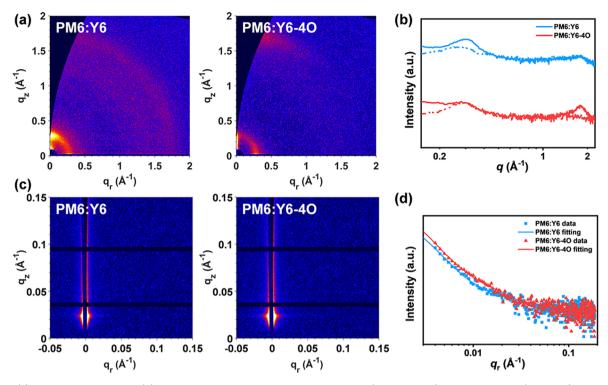


Figure 5. (a) 2D GIWAXS patterns, (b) GIWAXS intensity profiles along the in-plane (scattered line) and out-of-plane (solid line) directions, (c) 2D GISAXS patterns and (d) GISAXS intensity profiles and best fittings along the in-plane direction for PM6:Y6 and PM6:Y6-4O blend films.

formed at 580-630 nm, which match the absorption peaks of PM6. This rapidly formed PM6 GSB has been attributed to the ultrafast direct exciton dissociation via the hole transfer at the interfaces between the acceptor and donor domains, leading to the spatially separated charges.^{54–56} As the delay increased, the exciton bleach of the acceptors gradually decreased, accompanied by the growth of the PM6 GSB. It is worth noting that the nearly unchanged GSB signal at the first vibronic position in PM6:Y6 is probably due to the spectral overlap between the PM6 and Y6 absorption peaks in the corresponding blend, and at such a position, the growth of PM6 bleach is coincidentally canceled out by the decay of Y6 bleach. This relatively slower spectral evolution has been attributed to the interfacial dissociation of the excitons that migrate from the inside of the acceptor domains to the interfaces, which reflects the exciton diffusion in the acceptor domains.⁵⁵ In addition, the hole transfer from the acceptors to the donor also accounts for the ESA feature evolving into a broader positive feature, which has been ascribed to the spatially separated electrons and holes located in the acceptor and donor, respectively.^{54,57-59} Taking into account the electron-phonon interaction, these charge carriers can be treated as polarons. The Coulomb attraction can bind the oppositely signed polarons residing across the acceptor-donor interface as polaron pairs, which are then denoted as interfacial polaron pairs (i-PPs). On the basis of the previously described analysis, the amplitudes of the PM6 GSB and i-PP feature can be exploited to probe the charge separation (CS) yield in PM6:Y6 and PM6:Y6-4O. At a delay of ~ 0.2 ps, the direct interfacial hole transfer is completed, but negligible excitons created inside the acceptor domains diffuse to the interfaces. The bleach amplitude of the acceptors at this delay indicates the number of excitons, and we can assume that there is the same number of the excitons in the two samples by scaling their TA spectra together (Figure 4c). At a delay of \sim 80 ps, both the PM6 GSB and the i-PP feature reached maxima, which is indicative of the fact that the diffusionlimited hole transfer was completed. We found that the TA spectra of the two samples at 80 ps with the same scaling factor used in the Figure 4d showed distinct PM6 GSB amplitudes. The PM6 GSB for the PM6:Y6-4O is twice that for the PM6:Y6, suggesting the much higher CS yield in the former.

The CS yield can also be evaluated from the dynamic perspective. The direct interfacial hole transfer takes place on a subpicosecond time scale,⁵⁵ which is much shorter than the exciton lifetime in the acceptors. Thus the interfacial hole transfer should not limit the CS yield. On the contrary, the formed i-PPs can recombine across the boundary and relax to the ground state, which reduces the CS yield. Recently, studies have justified that the i-PPs can also relax to the triplet state of the acceptors, which has a detrimental impact on the device performance.^{53,57} The interfacial recombination can be suppressed if the i-PPs dissociate into further separated electron and hole polarons. For those excitons inside the domains, they also undergo bulk recombination during the diffusion process. Thus the CS yield is not only determined by the diffusion but also depends on the interfacial i-PP recombination and dissociation. As shown in Figure 4e, both the formation and decay of the PM6 GSB kinetics in PM6:Y6 were slightly faster than those in PM6:Y6-4O. The neat film measurement justifies that the exciton recombinations in both Y6 and Y6-4O domains are similar. Thus the faster formation of PM6 GSB in Y6-based OSCs is likely due to the shorter diffusion distance, which is confirmed by the later measurement of grazingincidence small-angle X-ray scattering (GISAXS). If only the diffusion process is considered, then the CS yield in PM6:Y6 should be slightly higher than that in PM6:Y6-4O, which seems to contradict the conclusion based on the spectral results. The interfacial i-PP dynamics should also be taken into

account. The exciton bleach recovery kinetics of acceptors in the two blend films are displayed in Figure 4f. At short delays, the exciton bleach of Y6 decayed significantly faster than that of Y6-4O, suggesting that compared with PM6:Y6-4O, more excited acceptors in PM6:Y6 return to the ground state via either exciton recombination or interfacial i-PP recombination. The former recombination channel depopulates the excited acceptors in the same rate, so this mechanism is ruled out. Thus the ultrafast i-PP recombination must account for the faster Y6 exciton bleach recovery. Therefore, we can now conclude that compared with PM6:Y6-4O, the lower CS yield in the PM6:Y6 is mainly due to the ultrafast interfacial i-PP recombination. Because a higher dielectric constant may cause smaller i-PP binding energy, which facilitates the i-PP dissociation and reduces the i-PP recombination probability, the higher dielectric constant of Y6-4O might be responsible for the higher CS yield in the PM6:Y6-4O.41

The surface morphology of PM6:Y6 and PM6:Y6-4O blend films was investigated by atomic force microscopy (AFM) (Figure S8). The PM6:Y6-4O blend film shows an obviously smaller root-mean-square roughness of 1.46 nm than that of the PM6:Y6 film (6.80 nm). A smoother surface is beneficial for the formation of better interfacial contact. Grazingincidence wide-angle X-ray scattering (GIWAXS) and GISAXS were used to explore the molecular packing and nanoscale phase separation of blend films, respectively.⁶⁰ The 2D GIWAXS patterns of neat and blend films and the corresponding out-of-plane (OOP)/in-plane (IP) linecut profiles are exhibited in Figure S9 and Figure 5, respectively. The PM6:Y6 blend film shows a strong OOP lamellar peak at $q_z = 0.302 \text{ Å}^{-1} (d = 20.8 \text{ Å})$ and a relatively weaker IP lamellar peak at $q_r = 0.276 \text{ Å}^{-1} (d = 22.8 \text{ Å})$, which originated from the edge-on oriented PM6 and the face-on oriented Y6 crystalline domains, respectively. On the contrary, the film of PM6:Y6-4O shows a preferential face-on orientation with a strong IP lamellar peak at $q_r = 0.284 \text{ Å}^{-1} (d = 22.1 \text{ Å})$ and a well-defined OOP $\pi - \pi$ stacking peak at $q_z = 1.81$ Å⁻¹ (d = 3.47 Å), and both peaks can be traced back to face-on oriented Y6-4O. In addition, 2D GISAXS patterns, the corresponding fitted intensity profiles in the IP direction, and the domain size data are shown in Figure 5 and Table S5. The acceptor domain sizes $(2R_{\sigma})$ of PM6:Y6 and PM6:Y6-4O blends are fitted to be 15.8 and 20.8 nm, respectively, which may explain the faster formation of PM6 GSB in PM6:Y6 blend films relative to Y6-40-based films.

Charge Recombination and Voltage Loss

The bimolecular recombination coefficient (β) can be defined by the following expression^{61,62}

$$\beta = \gamma k_{\rm L} = \left[\frac{16\pi}{9} \frac{\mu_{\rm e} \mu_{\rm h}}{\mu_{\rm double}^2 - (\mu_{\rm e} + \mu_{\rm h})^2}\right] \left[\frac{q(\mu_{\rm e} + \mu_{\rm h})}{\varepsilon_0 \varepsilon_{\rm r}}\right]$$

where γ is a dimensionless parameter, $k_{\rm L}$ is the Langevin rate constant, $\mu_{\rm double}$ is the effective mobility of the double carrier device, $\mu_{\rm h}$ and $\mu_{\rm e}$ are the hole and electron mobility in the blend films, and $\varepsilon_{\rm r}$ is the average value for the donor and acceptor (Figure S10). According to the results of the SCLC method (Figures S11 and S12), the PM6:Y6 blend film showed a $\mu_{\rm h}$ of 8.4 × 10⁻⁵ cm² V⁻¹ s⁻¹, a $\mu_{\rm e}$ of 0.74 × 10⁻⁵ cm² V⁻¹ s⁻¹, and a γ of 0.15. In contrast, the PM6:Y6-4O blend film exhibited more balanced mobilities ($\mu_{\rm h} = 3.2 \times 10^{-5}$ cm² V⁻¹ s⁻¹; $\mu_{\rm e} = 2.7 \times 10^{-5}$ cm² V⁻¹ s⁻¹) and a much smaller γ of

0.017. As a result, β can be calculated as 7.2×10^{-18} m³ s⁻¹ for PM6:Y6 and 4.4×10^{-19} m³ s⁻¹ for PM6:Y6-4O, respectively. Because of the higher ε_r and the more balanced charge-carrier transport, PM6:Y6-4O exhibited a smaller bimolecular recombination coefficient, which can notably reduce the charge recombination and further lead to a higher $J_{\rm SC}$. According to the previous work, the decreased bimolecular recombination loss related to a larger dielectric constant can play an important role in lowering the open-circuit voltage loss ($V_{\rm loss}$) of OSC devices, which is defined as the difference between the $E_{\rm g}^{\rm PV}/q$ and the $V_{\rm OC}$.^{63,64} PM6:Y6-4O-based devices exhibited a smaller $V_{\rm loss}$ of 0.57 V relative to PM6:Y6-based devices ($V_{\rm loss} = 0.59$ V). The larger dielectric constant of Y6-4O leads to a smaller $V_{\rm loss}$ of PM6:Y6-4O based devices, which is beneficial for the higher $V_{\rm OC}$ and PCE.

CONCLUSIONS

In summary, we used a rational molecular design strategy to simultaneously enhance the permittivity and ecocompatibility of the high-performance electron acceptor Y6 through introducing an asymmetric highly polarizable OEG chain onto the pyrrole unit. Compared with Y6 ($\varepsilon_r = 3.36$), Y6-4O with a larger dipole moment had a higher dielectric constant of 5.13 and excellent solubility in nonhalogen solvents. The higher ε_r value had a negligible impact on the optical property, energy levels, and exciton lifetime of Y6-4O but led to more efficient exciton dissociation, slower bimolecular recombination kinetics, and less voltage loss of the toluene-processed devices based on as-cast PM6:Y6-4O. Consequently, a high PCE of 15.2% was achieved for PM6:Y6-4O based devices, much higher than that of the control devices based on PM6:Y6 (7.38%). It is worth noting that 15.2% is the highest PCE for the as-cast nonhalogenated processed OSC devices and the record PCE for OSCs based on high-permittivity ($\varepsilon_r > 5$) organic semiconductors. These results imply that the strategy of asymmetric substitution with an OEG side chain can simultaneously enhance the dielectric constant and the solubility of organic semiconductors, which is very promising for achieving high performance in ecofriendly solventprocessed OSC devices.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/jacsau.1c00306.

Detailed experimental procedures including materials, synthesis, characterization, device fabrication and characterization, femtosecond transient absorption, and mobility measurements, additional characterization data, Scheme S1, Figure S1–S12, and Table S1–S5 (PDF)

AUTHOR INFORMATION

Corresponding Authors

- Yuze Lin Beijing National Laboratory for Molecular Sciences, CAS Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China; University of Chinese Academy of Sciences, Beijing 100049, China; ◎ orcid.org/0000-0002-0325-3842; Email: linyz@iccas.ac.cn
- Ye Yang State Key Laboratory of Physical Chemistry of Solid Surfaces, College of Chemistry and Chemical Engineering,

Xiamen University, Xiamen 361005, China; o orcid.org/ 0000-0003-2827-3572; Email: ye.yang@xmu.edu.cn

Authors

- Tengfei Li Beijing National Laboratory for Molecular Sciences, CAS Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China
- Kang Wang State Key Laboratory of Physical Chemistry of Solid Surfaces, College of Chemistry and Chemical Engineering, Xiamen University, Xiamen 361005, China
- Guilong Cai Department of Physics, The Chinese University of Hong Kong, 999077 Hong Kong, China; Orcid.org/ 0000-0001-9924-1362
- Yawen Li Beijing National Laboratory for Molecular Sciences, CAS Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China
- Heng Liu Department of Physics, The Chinese University of Hong Kong, 999077 Hong Kong, China
- Yixiao Jia Beijing National Laboratory for Molecular Sciences, CAS Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China
- Zhenzhen Zhang Beijing National Laboratory for Molecular Sciences, CAS Key Laboratory of Organic Solids, Institute of Chemistry, Chinese Academy of Sciences, Beijing 100190, China; University of Chinese Academy of Sciences, Beijing 100049, China
- Xinhui Lu Department of Physics, The Chinese University of Hong Kong, 999077 Hong Kong, China

Complete contact information is available at: https://pubs.acs.org/10.1021/jacsau.1c00306

Notes

The authors declare no competing financial interest.

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REFERENCES

(1) Yu, G.; Gao, J.; Hummelen, J. C.; Wudl, F.; Heeger, A. J. Polymer photovoltaic cells - enhanced efficiencies via a network of internal donor-acceptor heterojunctions. *Science* **1995**, *270*, 1789–1791.

(2) Lu, L.; Zheng, T.; Wu, Q.; Schneider, A. M.; Zhao, D.; Yu, L. Recent advances in bulk heterojunction polymer solar cells. *Chem. Rev.* **2015**, *115*, 12666–12731.

(3) Li, T.; Zhan, X. Advances in organic photovoltaics. *Huaxue Xuebao* 2021, 79, 257.

(4) Cheng, P.; Yang, Y. Narrowing the band gap: The key to highperformance organic photovoltaics. *Acc. Chem. Res.* **2020**, *53*, 1218– 1228.

(5) Yan, C.; Barlow, S.; Wang, Z.; Yan, H.; Jen, A. K.-Y.; Marder, S. R.; Zhan, X. Non-fullerene acceptors for organic solar cells. *Nat. Rev. Mater.* **2018**, *3*, 18003.

(6) Zhang, G.; Zhao, J.; Chow, P. C. Y.; Jiang, K.; Zhang, J.; Zhu, Z.; Zhang, J.; Huang, F.; Yan, H. Nonfullerene acceptor molecules for bulk heterojunction organic solar cells. *Chem. Rev.* **2018**, *118*, 3447–3507.

(7) Lin, Y.; Wang, J.; Zhang, Z. G.; Bai, H.; Li, Y.; Zhu, D.; Zhan, X. An electron acceptor challenging fullerenes for efficient polymer solar cells. *Adv. Mater.* **2015**, *27*, 1170–1174.

(8) Zhao, W.; Li, S.; Yao, H.; Zhang, S.; Zhang, Y.; Yang, B.; Hou, J. Molecular optimization enables over 13% efficiency in organic solar cells. *J. Am. Chem. Soc.* **2017**, *139*, 7148–7151.

(9) Li, T.; Dai, S.; Ke, Z.; Yang, L.; Wang, J.; Yan, C.; Ma, W.; Zhan, X. Fused tris(thienothiophene)-based electron acceptor with strong near-infrared absorption for high-performance as-cast solar cells. *Adv. Mater.* **2018**, *30*, 1705969.

(10) Li, X.; Pan, F.; Sun, C.; Zhang, M.; Wang, Z.; Du, J.; Wang, J.; Xiao, M.; Xue, L.; Zhang, Z. G.; Zhang, C.; Liu, F.; Li, Y. Simplified synthetic routes for low cost and high photovoltaic performance n-type organic semiconductor acceptors. *Nat. Commun.* **2019**, *10*, 519.

(11) Jiang, K.; Wei, Q.; Lai, J. Y. L.; Peng, Z.; Kim, H. K.; Yuan, J.; Ye, L.; Ade, H.; Zou, Y.; Yan, H. Alkyl chain tuning of small molecule acceptors for efficient organic solar cells. *Joule* **2019**, *3*, 3020–3033.

(12) Meng, L.; Zhang, Y.; Wan, X.; Li, C.; Zhang, X.; Wang, Y.; Ke, X.; Xiao, Z.; Ding, L.; Xia, R.; Yip, H.-L.; Cao, Y.; Chen, Y. Organic and solution-processed tandem solar cells with 17.3% efficiency. *Science* **2018**, *361*, 1094–1098.

(13) Yuan, J.; Zhang, Y.; Zhou, L.; Zhang, G.; Yip, H.-L.; Lau, T.-K.; Lu, X.; Zhu, C.; Peng, H.; Johnson, P. A.; Leclerc, M.; Cao, Y.; Ulanski, J.; Li, Y.; Zou, Y. Single-junction organic solar cell with over 15% efficiency using fused-ring acceptor with electron-deficient core. *Joule* **2019**, *3*, 1140–1151.

(14) Liu, S.; Yuan, J.; Deng, W.; Luo, M.; Xie, Y.; Liang, Q.; Zou, Y.; He, Z.; Wu, H.; Cao, Y. High-efficiency organic solar cells with low non-radiative recombination loss and low energetic disorder. *Nat. Photonics* **2020**, *14*, 300–305.

(15) Li, Y.; Zhang, Z.; Han, X.; Li, T.; Lin, Y. Fine-tuning contact via complexation for high-performance organic solar cells. *CCS Chem.* **2021**, *3*, 1206–1216.

(16) Zhang, Y.; Cai, G.; Li, Y.; Zhang, Z.; Li, T.; Zuo, X.; Lu, X.; Lin, Y. An electron acceptor analogue for lowering trap density in organic solar cells. *Adv. Mater.* **2021**, *33*, 2008134.

(17) Ma, Y.; Zhang, M.; Wan, S.; Yin, P.; Wang, P.; Cai, D.; Liu, F.; Zheng, Q. Efficient organic solar cells from molecular orientation control of m-series acceptors. *Joule* **2021**, *5*, 197–209.

(18) Nian, L.; Kan, Y. Y.; Gao, K.; Zhang, M.; Li, N.; Zhou, G. Q.; Jo, S. B.; Shi, X. L.; Lin, F.; Rong, Q. K.; Liu, F.; Zhou, G. F.; Jen, A. K. Y. Approaching 16% efficiency in all-small-molecule organic solar cells based on ternary strategy with a highly crystalline acceptor. *Joule* **2020**, *4*, 2223–2236.

(19) Zhang, Z.; Li, Y.; Cai, G.; Zhang, Y.; Lu, X.; Lin, Y. Selenium heterocyclic electron acceptor with small urbach energy for as-cast high-performance organic solar cells. *J. Am. Chem. Soc.* **2020**, *142*, 18741–18745.

(20) Liu, Q.; Jiang, Y.; Jin, K.; Qin, J.; Xu, J.; Li, W.; Xiong, J.; Liu, J.; Xiao, Z.; Sun, K.; Yang, S.; Zhang, X.; Ding, L. 18% efficiency organic solar cells. *Sci. Bull.* **2020**, *65*, 272–275.

(21) Green, M. A.; Dunlop, E. D.; Hohl-Ebinger, J.; Yoshita, M.; Kopidakis, N.; Ho-Baillie, A. W. Y. Solar cell efficiency tables (version 55). *Prog. Photovoltaics* **2020**, *28*, 3–15.

(22) Koster, L. J. A.; Shaheen, S. E.; Hummelen, J. C. Pathways to a new efficiency regime for organic solar cells. *Adv. Energy Mater.* **2012**, *2*, 1246–1253.

(23) Samiee, M.; Konduri, S.; Ganapathy, B.; Kottokkaran, R.; Abbas, H. A.; Kitahara, A.; Joshi, P.; Zhang, L.; Noack, M.; Dalal, V. Defect density and dielectric constant in perovskite solar cells. *Appl. Phys. Lett.* **2014**, *105*, 153502.

(24) Gregg, B. A.; Hanna, M. C. Comparing organic to inorganic photovoltaic cells: Theory, experiment, and simulation. *J. Appl. Phys.* **2003**, *93*, 3605–3614.

(25) Gledhill, S. E.; Scott, B.; Gregg, B. A. Organic and nanostructured composite photovoltaics: An overview. *J. Mater. Res.* 2005, 20, 3167–3179.

(26) Liu, X.; Xie, B. M.; Duan, C. H.; Wang, Z. J.; Fan, B. B.; Zhang, K.; Lin, B. J.; Colberts, F. J. M.; Ma, W.; Janssen, R. A. J.; Huang, F.; Cao, Y. A high dielectric constant non-fullerene acceptor for efficient bulk-heterojunction organic solar cells. *J. Mater. Chem. A* **2018**, *6*, 395–403.

(27) Brebels, J.; Manca, J. V.; Lutsen, L.; Vanderzande, D.; Maes, W. High dielectric constant conjugated materials for organic photo-voltaics. *J. Mater. Chem. A* **2017**, *5*, 24037–24050.

(28) Cho, N.; Schlenker, C. W.; Knesting, K. M.; Koelsch, P.; Yip, H. L.; Ginger, D. S.; Jen, A. K. Y. High-dielectric constant side-chain polymers show reduced non-geminate recombination in heterojunction solar cells. *Adv. Energy Mater.* **2014**, *4*, 1301857.

(29) Jahani, F.; Torabi, S.; Chiechi, R. C.; Koster, L. J. A.; Hummelen, J. C. Fullerene derivatives with increased dielectric constants. *Chem. Commun.* **2014**, *50*, 10645–10647.

(30) Zhang, S.; Zhang, Z. J.; Liu, J.; Wang, L. X. Fullerene adducts bearing cyano moiety for both high dielectric constant and good active layer morphology of organic photovoltaics. *Adv. Funct. Mater.* **2016**, *26*, 6107–6113.

(31) Chen, X.; Zhang, Z.; Ding, Z.; Liu, J.; Wang, L. Diketopyrrolopyrrole-based conjugated polymers bearing branched oligo(ethylene glycol) side chains for photovoltaic devices. *Angew. Chem., Int. Ed.* **2016**, *55*, 10376–10380.

(32) Armin, A.; Stoltzfus, D. M.; Donaghey, J. E.; Clulow, A. J.; Nagiri, R. C. R.; Burn, P. L.; Gentle, I. R.; Meredith, P. Engineering dielectric constants in organic semiconductors. *J. Mater. Chem. C* **2017**, *5*, 3736–3747.

(33) Jang, B.; Lee, C.; Lee, Y. W.; Kim, D.; Uddin, M. A.; Kim, F. S.; Kim, B. J.; Woo, H. Y. A high dielectric n-type small molecular acceptor containing oligoethyleneglycol side-chains for organic solar cells. *Chin. J. Chem.* **2018**, *36*, 199–205.

(34) Zhang, S.; Ye, L.; Zhang, H.; Hou, J. Green-solvent-processable organic solar cells. *Mater. Today* **2016**, *19*, 533–543.

(35) Volksen, W.; Miller, R. D.; Dubois, G. Low dielectric constant materials. *Chem. Rev.* **2010**, *110*, 56–110.

(36) Zhang, X.; Zhang, D.; Zhou, Q.; Wang, R.; Zhou, J.; Wang, J.; Zhou, H.; Zhang, Y. Fluorination with an enlarged dielectric constant prompts charge separation and reduces bimolecular recombination in non-fullerene organic solar cells with a high fill factor and efficiency > 13%. *Nano Energy* **2019**, *56*, 494–501.

(37) Wudarczyk, J.; Papamokos, G.; Margaritis, V.; Schollmeyer, D.; Hinkel, F.; Baumgarten, M.; Floudas, G.; Mullen, K. Hexasubstituted benzenes with ultrastrong dipole moments. *Angew. Chem., Int. Ed.* **2016**, 55, 3220–3223.

(38) Lin, Y.; He, Q.; Zhao, F.; Huo, L.; Mai, J.; Lu, X.; Su, C. J.; Li, T.; Wang, J.; Zhu, J.; Sun, Y.; Wang, C.; Zhan, X. A facile planar fused-ring electron acceptor for as-cast polymer solar cells with 8.71% efficiency. *J. Am. Chem. Soc.* **2016**, *138*, 2973–2976.

(39) Dai, S.; Zhao, F.; Zhang, Q.; Lau, T. K.; Li, T.; Liu, K.; Ling, Q.; Wang, C.; Lu, X.; You, W.; Zhan, X. Fused nonacyclic electron acceptors for efficient polymer solar cells. *J. Am. Chem. Soc.* **2017**, *139*, 1336–1343.

(40) Torabi, S.; Jahani, F.; Van Severen, I.; Kanimozhi, C.; Patil, S.; Havenith, R. W. A.; Chiechi, R. C.; Lutsen, L.; Vanderzande, D. J. M.; Cleij, T. J.; Hummelen, J. C.; Koster, L. J. A. Strategy for enhancing the dielectric constant of organic semiconductors without sacrificing charge carrier mobility and solubility. *Adv. Funct. Mater.* **2015**, *25*, 150–157.

(41) Clarke, T. M.; Durrant, J. R. Charge photogeneration in organic solar cells. *Chem. Rev.* **2010**, *110*, 6736–6767.

(42) Bredas, J.-L. Mind the gap! Mater. Horiz. 2014, 1, 17-19.

(43) Yao, J.; Qiu, B.; Zhang, Z. G.; Xue, L.; Wang, R.; Zhang, C.; Chen, S.; Zhou, Q.; Sun, C.; Yang, C.; Xiao, M.; Meng, L.; Li, Y. Cathode engineering with perylene-diimide interlayer enabling over 17% efficiency single-junction organic solar cells. *Nat. Commun.* **2020**, *11*, 2726.

(44) Leblebici, S. Y.; Chen, T. L.; Olalde-Velasco, P.; Yang, W.; Ma, B. Reducing exciton binding energy by increasing thin film permittivity: An effective approach to enhance exciton separation efficiency in organic solar cells. *ACS Appl. Mater. Interfaces* **2013**, *5*, 10105–10110.

(45) Malliaras, G. G.; Salem, J. R.; Brock, P. J.; Scott, C. Electrical characteristics and efficiency of single-layer organic light-emitting diodes. *Phys. Rev. B: Condens. Matter Mater. Phys.* **1998**, *58*, R13411.

(46) Zhang, M.; Guo, X.; Ma, W.; Ade, H.; Hou, J. A large-bandgap conjugated polymer for versatile photovoltaic applications with high performance. *Adv. Mater.* **2015**, *27*, 4655–4660.

(47) Lu, L.; Xu, T.; Chen, W.; Landry, E. S.; Yu, L. Ternary blend polymer solar cells with enhanced power conversion efficiency. *Nat. Photonics* **2014**, *8*, 716–722.

(48) Chen, S.; Wang, Y.; Zhang, L.; Zhao, J.; Chen, Y.; Zhu, D.; Yao, H.; Zhang, G.; Ma, W.; Friend, R. H.; Chow, P. C. Y.; Gao, F.; Yan, H. Efficient nonfullerene organic solar cells with small driving forces for both hole and electron transfer. *Adv. Mater.* **2018**, *30*, 1804215.

(49) Rau, U.; Blank, B.; Muller, T. C. M.; Kirchartz, T. Efficiency potential of photovoltaic materials and devices unveiled by detailed-balance analysis. *Phys. Rev. Appl.* **2017**, *7*, No. 044016.

(50) Karki, A.; Vollbrecht, J.; Dixon, A. L.; Schopp, N.; Schrock, M.; Reddy, G. N. M.; Nguyen, T. Q. Understanding the high performance of over 15% efficiency in single-junction bulk heterojunction organic solar cells. *Adv. Mater.* **2019**, *31*, 1903868.

(51) Wang, Y.; Jia, B.; Wang, J.; Xue, P.; Xiao, Y.; Li, T.; Wang, J.; Lu, H.; Tang, Z.; Lu, X.; Huang, F.; Zhan, X. High-efficiency perovskite quantum dot hybrid nonfullerene organic solar cells with near-zero driving force. *Adv. Mater.* **2020**, *32*, 2002066.

(52) Bakulin, A. A.; Rao, A.; Pavelyev, V. G.; van Loosdrecht, P. H. M.; Pshenichnikov, M. S.; Niedzialek, D.; Cornil, J.; Beljonne, D.; Friend, R. H. The role of driving energy and delocalized states for charge separation in organic semiconductors. *Science* **2012**, *335*, 1340–1344.

(53) Wang, R.; Xu, J.; Fu, L.; Zhang, C.; Li, Q.; Yao, J.; Li, X.; Sun, C.; Zhang, Z. G.; Wang, X.; Li, Y.; Ma, J.; Xiao, M. Nonradiative triplet loss suppressed in organic photovoltaic blends with fluoridated nonfullerene acceptors. J. Am. Chem. Soc. **2021**, 143, 4359–4366.

(54) Wang, R.; Zhang, C.; Li, Q.; Zhang, Z.; Wang, X.; Xiao, M. Charge separation from an intra-moiety intermediate state in the high-performance pm6:Y6 organic photovoltaic blend. *J. Am. Chem. Soc.* **2020**, *142*, 12751–12759.

(55) Chen, Z.; Chen, X.; Qiu, B.; Zhou, G.; Jia, Z.; Tao, W.; Li, Y.; Yang, Y. M.; Zhu, H. Ultrafast hole transfer and carrier transport controlled by nanoscale-phase morphology in nonfullerene organic solar cells. J. Phys. Chem. Lett. **2020**, *11*, 3226–3233.

(56) Niu, M.-S.; Wang, K.-W.; Yang, X.-Y.; Bi, P.-Q.; Zhang, K.-N.; Feng, X.-J.; Chen, F.; Qin, W.; Xia, J.-L.; Hao, X.-T. Hole transfer originating from weakly bound exciton dissociation in acceptor– donor–acceptor nonfullerene organic solar cells. *J. Phys. Chem. Lett.* **2019**, *10*, 7100–7106.

(57) Chen, Z.; Chen, X.; Jia, Z. Y.; Zhou, G. Q.; Xu, J. Q.; Wu, Y. X.; Xia, X. X.; Li, X. F.; Zhang, X. N.; Deng, C.; Zhang, Y.; Lu, X. H.; Liu, W. M.; Zhang, C. F.; Yang, Y.; Zhu, H. M. Triplet exciton formation for non-radiative voltage loss in high-efficiency nonfullerene organic solar cells. *Joule* **2021**, *5*, 1832–1844.

(58) Wang, K.; Chen, H.; Zhang, J.; Zou, Y.; Yang, Y. Intrachain and interchain exciton–exciton annihilation in donor–acceptor copolymers. *J. Phys. Chem. Lett.* **2021**, *12*, 3928–3933.

(59) Zhou, G.; Ding, H.; Zhu, L.; Qiu, C.; Zhang, M.; Hao, T.; Feng, W.; Zhang, Y.; Zhu, H.; Liu, F. Photophysics, morphology and device performances correlation on non-fullerene acceptor based binary and ternary solar cells. *J. Energy Chem.* **2020**, *47*, 180–187.

(60) Mai, J.; Lau, T.-K.; Li, J.; Peng, S.-H.; Hsu, C.-S.; Jeng, U. S.; Zeng, J.; Zhao, N.; Xiao, X.; Lu, X. Understanding morphology compatibility for high-performance ternary organic solar cells. *Chem. Mater.* **2016**, *28*, 6186–6195.

(61) Langevin, P. Recombinaison et mobilites des ions dans les gaz. Ann. Chim. Phys. **1903**, 28 (7), 433.

(62) Wetzelaer, G.-J. A. H.; Van der Kaap, N. J.; Koster, L. J. A.; Blom, P. W. M. Quantifying bimolecular recombination in organic solar cells in steady state. *Adv. Energy Mater.* **2013**, *3*, 1130–1134.

(63) Fu, Z.; Zhang, X.; Zhang, H.; Li, Y.; Zhou, H.; Zhang, Y. On the understandings of dielectric constant and its impacts on the photovoltaic efficiency in organic solar cells. *Chin. J. Chem.* **2021**, *39*, 381–390.

(64) Collins, S. D.; Proctor, C. M.; Ran, N. A.; Nguyen, T.-Q. Understanding open-circuit voltage loss through the density of states in organic bulk heterojunction solar cells. *Adv. Energy Mater.* **2016**, *6*, 1501721.